

37 CFR 1.501
 INFORMATION DISCLOSURE STATEMENT
 IN A PATENT
 (use several sheets if necessary)



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Serial No.
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Applicants:
 Dharam Pal Gosain

Filing Date
 August 21, 2003

Group Art Unit
 2813

U.S. PATENT DOCUMENTS

Examiner's Initials		Document Number	Date	Country	Class	Subclass	Filing Date If appropriate
	AA						
	AB						
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FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
	AH							
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	AQ							
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

<i>de</i>	AU	Australian Search Report <i>unavailable</i>
<i>1</i>	AV	Derwent Abstract Accession No. 89-351354/48, Class U11, JP 01-261291 A (Agency of Ind Sci Tech) 18 October 1989 Abstract (Relevant to Claim No. 1-37).
<i>1</i>	AW	SMITH et al, 'Silicon-on-insulator by graphoepitaxy and zone-melting recrystallization of patterned films', Journal of Crystal Growth, North-Holland, 1983, vol. 73, pages 527-546 Section 3 (Relevant to Claim No. 1-37).
<i>2</i>	AX	ISHIHARA, R.K., 'Location control of laterally columnar Si grains by dual-beam excimer-laser melting of Si thin-film', Materials Research Society Symposium Proceedings, 2000, vol. 621, pages Q9.4.1-Q9.4.6. Whole document (Relevant to Claim No. 1-37).
	AY	

Examiner

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Date Considered

11/13/05

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.